Preliminary TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC74LCXZ16240FT

Low-Voltage 16-Bit Bus Buffer (inverted) with 5-V Tolerant Inputs and Outputs

The TC74LCXZ16240FT is a high-performance CMOS 16-bit bus buffer. Designed for use in 3.3-V systems, it achieves high-speed operation while maintaining the CMOS low power dissipation.

The device is designed for low-voltage (3.3 V) VCC applications, but it could be used to interface to 5-V supply environment for both inputs and outputs.

This device is inverting 3-state buffer having four active-low output enables. It can be used as four 4-bit buffers two 8-bit buffers or one 16-bit buffer. When the OE input is high, the outputs are in a high-impedance state. This device is designed to be used with 3-state memory address drivers, etc.



Weight: 0.25 g (typ.)

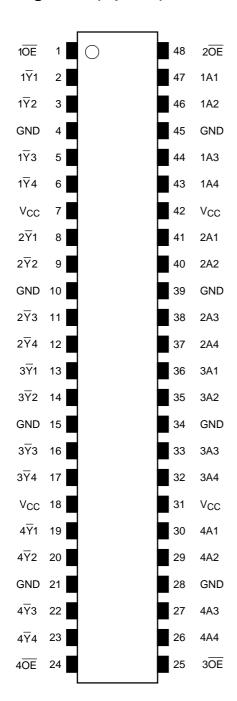
When VCC is between 0 and 1.5 V, the LCXZ16240 is in the high-impedance state during power up or power down. This place the outputs in high-impedance (Z) state preventing intermittent low-impedance loading or glitching in bus oriented applications.

All inputs are equipped with protection circuits against static discharge.

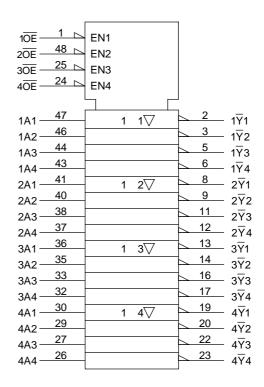
Features

- Low-voltage operation: VCC = 2.7 to 3.6 V
- High-speed operation: $t_{pd} = 4.5 \text{ ns (max) (VCC} = 3.0 \text{ to } 3.6 \text{ V)}$
- Output current: $|I_{OH}|/I_{OL} = 24 \text{ mA (min) (V}_{CC} = 3.0 \text{ V)}$
- Latch-up performance: ±500 mA
- Package: TSSOP (thin shrink small outline package)
- · Power-down protection provided on all inputs and outputs
- Supports live insersion/withdrawal: guaranteed power up/down high impedance

Pin Assignment (top view)



IEC Logic Symbol



2

Truth Table

Inp	uts	Outputs
1OE	1A1-1A4	1 <u>7</u> 1 - 1 <u>7</u> 4
L	L	Н
L	Н	L
Н	Х	Z

Inp	uts	Outputs
2 OE	2A1-2A4	2 <u>Y</u> 1 - 2 <u>Y</u> 4
L	L	Н
L	Н	L
Н	Х	Z

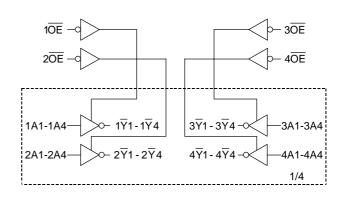
Inp	uts	Outputs
3 OE	3A1-3A4	3 <u>Y</u> 1 - 3 <u>Y</u> 4
L	L	Н
L	Н	L
Н	Х	Z

Inp	uts	Outputs
4 OE	4A1-4A4	4 <u>Y</u> 1 - 4 <u>Y</u> 4
L	L	Н
L	Н	L
Н	Х	Z

X: Don't care

Z: High impedance

System Diagram



3



Maximum Ratings

Characteristics	Symbol	Rating	Unit
Power supply voltage	V _{CC}	-0.5 to 7.0	V
Input voltage	V _{IN}	-0.5 to 7.0	V
		-0.5 to 7.0 (Note 1)	
Output voltage	V _{OUT}	-0.5 to V _{CC} + 0.5	V
		(Note 2)	
Input diode current	I _{IK}	-50	mA
Output diode current	I _{OK}	±50 (Note 3)	mA
DC output current	lout	±50	mA
Power dissipation	P _D	400	mW
DC V _{CC} /ground current per supply pin	I _{CC} /I _{GND}	±100	mA
Storage temperature	T _{stg}	-65 to 150	

Note 1: Outputs in OFF state or $V_{CC} = 0$ to 1.5 V

Note 2: High or low state. $I_{\mbox{OUT}}$ absolute maximum rating must be observed.

Note 3: $V_{OUT} < GND, V_{OUT} > V_{CC}$

Recommended Operating Range

Characteristics	Symbol	Rating		
Power supply voltage	V _{CC}	2.7 to 3.6	V	
Input voltage	V _{IN}	0 to 5.5	V	
Output voltage	Vour	0 to 5.5 (Note 4)	V	
Output voltage	Vout	0 to V _{CC} (Note 5)		
Output current	lou/lou	±24 (Note 6)	mA	
Output current	I _{OH} /I _{OL}	±12 (Note 7)	IIIA	
Operating temperature	T _{opr}	-40 to 85	°C	
Input rise and fall time	dt/dv	0 to 10 (Note 8)	ns/V	

Note 4: Outputs OFF state or $V_{CC} = 0$ to 1.5 V

Note 5: High or low state

Note 6: $V_{CC} = 3.0 \text{ to } 3.6 \text{ V}$

Note 7: $V_{CC} = 2.7 \text{ to } 3.0 \text{ V}$

Note 8: $V_{IN} = 0.8$ to 2.0 V, $V_{CC} = 3.0$ V



Electrical Characteristics

DC Characteristics ($Ta = -40 \text{ to } 85^{\circ}\text{C}$)

Characterist	Characteristics Symbol Test Condition		Test Condition		symbol Test Condition			Min	Max	Unit
Onaracionsi	1103	Cymbol	1631 00	rest condition		141111				
Input voltage	H-level	VIH		_	2.7 to 3.6	2.0	_	V		
input voltage	L-level	V _{IL}	_	_	2.7 to 3.6	_	0.8	V		
				$I_{OH} = -100 \mu A$	2.7 to 3.6	V _{CC} -0.2				
	H-level	Voн	V _{IN} = V _{IH} or V _{IL}	I _{OH} = -12 μA	2.7	2.2	_			
				I _{OH} = -18 mA	3.0	2.4	_			
Output voltage				I _{OH} = -24 mA	3.0	2.2	_	V		
				I _{OL} = 100 μA	2.7 to 3.6	_	0.2			
	L-level	Va	V_{OL} $V_{IN} = V_{IH}$ or V_{IL}	I _{OL} = 12 mA	2.7	_	0.4			
	L-level	VOL		I _{OL} = 16 mA	3.0	_	0.4			
				$I_{OL} = 24 \text{ mA}$	3.0	_	0.55			
Input leakage current		I _{IN}	V _{IN} = 0 to 5.5 V		2.7 to 3.6	_	±5.0	μΑ		
3-state output OFF sta	ate current	loz	$V_{IN} = V_{IH} \text{ or } V_{IL}$ $V_{OUT} = 0 \text{ to } 5.5 \text{ V}$		2.7 to 3.6	_	±5.0	μА		
Power-off leakage cur	rent	l _{OFF}	$V_{IN}/V_{OUT} = 5.5 V$		0	_	10.0	μА		
Power up/down OFF s	state current	I _{PU/PD}	$V_{OUT} = 0.5 \text{ to } V_{CC}$ $V_{IN} = V_{CC} \text{ or GND}$		0 to 1.5	_	±5.0	μА		
		l	V _{IN} = V _{CC} or GND		2.7 to 3.6	_	225			
Quiescent supply current ICC V _{IN} /		$V_{IN}/V_{OUT} = 3.6 \text{ to } 5.5 \text{ V}$	/ (Note 9)	2.7 to 3.6	_	±225	μΑ			
		Δlcc	$V_{IH} = V_{CC} - 0.6 V$ (per	input)	2.7 to 3.6	_	500			

Note 9: Outputs high impedance



AC Characteristics ($Ta = -40 \text{ to } 85^{\circ}\text{C}$)

Characteristics	Symbol	Test Condition		Min	Max	Unit
			V _{CC} (V)			
Propagation delay time	t _{pLH}	Figure 1, Figure 2	2.7	1.0	5.3	ns
r repugation dotay time	t _{pHL}	1.194.0 1, 1.194.0 2	3.3 ± 0.3	1.0	4.5	110
3-state output enable time	t _{pZL}	Figure 1, Figure 3	2.7	1.0	6.0	ns
5-state output enable time	t _{pZH}		3.3 ± 0.3	1.0	5.4	113
3-state output disable time	t _{pLZ}	Figure 1, Figure 3	2.7	1.0	5.4	ns
5-state output disable time	t _{pHZ}	rigule 1, rigule 3	3.3 ± 0.3	1.0	5.3	113
Output to output skew	t _{osLH}	(Note 10)	2.7		_	ns
Output to output skew	t _{osHL}	(Note 10)	3.3 ± 0.3	_	1.0	10

Note 10: Parameter guaranteed by design.

 $(t_{OSLH} = |t_{PLHm} - t_{PLHn}|, t_{OSHL} = |t_{PHLm} - t_{PHLn}|)$

Dynamic Switching Characteristics

(Ta = 25°C, input: $t_r = t_f = 2.5 \text{ ns}$, $C_L = 50 \text{ pF}$, $R_L = 500 \Omega$)

Characteristics	Symbol	Test Condition	V _{CC} (V)	Тур.	Unit
Quiet output maximum dynamic V _{OL}	V _{OLP}	$V_{IH} = 3.3 \text{ V}, V_{IL} = 0 \text{ V}$	3.3	8.0	V
Quiet output minimum dynamic V _{OL}	V _{OLV}	V _{IH} = 3.3 V, V _{IL} = 0 V	3.3	0.8	V

Capacitive Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition		V _{CC} (V)	Тур.	Unit
Input capacitance	C _{IN}	_		3.3	7	pF
Output capacitance	C _{OUT}	_		3.3	8	pF
Power dissipation capacitance	C _{PD}	f _{IN} = 10 MHz	(Note 11)	3.3	25	pF

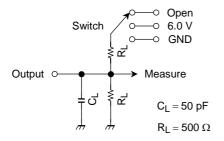
Note 11: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

6

Average operating current can be obtained by the equation:

 $I_{CC (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/16 \text{ (per bit)}$

AC Test Circuit



Parameter	Switch
t _{pLH} , t _{pHL}	Open
t _{pLZ} , t _{pZL}	6.0 V
t _{pHZ} , t _{pZH}	GND

Figure 1

AC Waveform

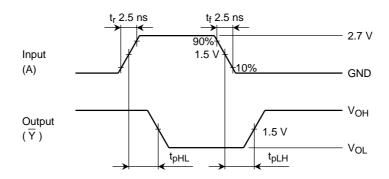


Figure 2 t_{pLH}, t_{pHL}

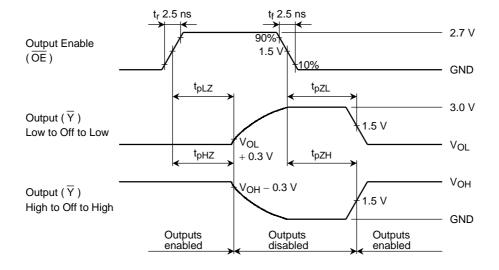
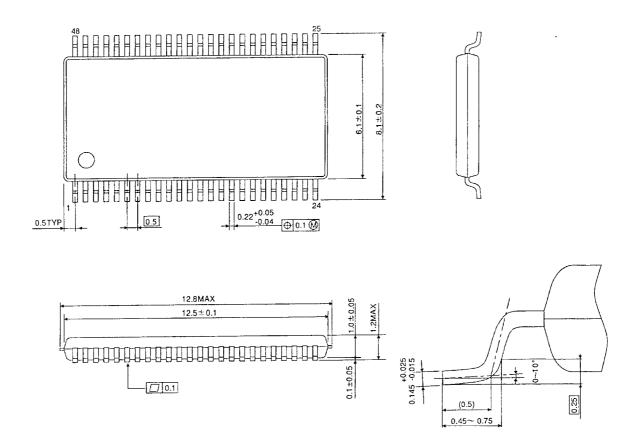


Figure 3 t_{pLZ} , t_{pHZ} , t_{pZL} , t_{pZH}

Package Dimensions

TOSHIBA

TSSOP48-P-0061-0.50 Unit: mm



Weight: 0.25 g (typ.)

RESTRICTIONS ON PRODUCT USE

000707EBA

- TOSHIBA is continually working to improve the quality and reliability of its products. Nevertheless, semiconductor devices in general can malfunction or fail due to their inherent electrical sensitivity and vulnerability to physical stress. It is the responsibility of the buyer, when utilizing TOSHIBA products, to comply with the standards of safety in making a safe design for the entire system, and to avoid situations in which a malfunction or failure of such TOSHIBA products could cause loss of human life, bodily injury or damage to property.
 In developing your designs, please ensure that TOSHIBA products are used within specified operating ranges as set forth in the most recent TOSHIBA products specifications. Also, please keep in mind the precautions and conditions set forth in the "Handling Guide for Semiconductor Devices," or "TOSHIBA Semiconductor Reliability Handbook" etc..
- The TOSHIBA products listed in this document are intended for usage in general electronics applications (computer, personal equipment, office equipment, measuring equipment, industrial robotics, domestic appliances, etc.). These TOSHIBA products are neither intended nor warranted for usage in equipment that requires extraordinarily high quality and/or reliability or a malfunction or failure of which may cause loss of human life or bodily injury ("Unintended Usage"). Unintended Usage include atomic energy control instruments, airplane or spaceship instruments, transportation instruments, traffic signal instruments, combustion control instruments, medical instruments, all types of safety devices, etc.. Unintended Usage of TOSHIBA products listed in this document shall be made at the customer's own risk.
- The products described in this document are subject to the foreign exchange and foreign trade laws.
- The information contained herein is presented only as a guide for the applications of our products. No responsibility is assumed by TOSHIBA CORPORATION for any infringements of intellectual property or other rights of the third parties which may result from its use. No license is granted by implication or otherwise under any intellectual property or other rights of TOSHIBA CORPORATION or others.
- The information contained herein is subject to change without notice.